TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT573P,TC74ACT573F,TC74ACT573FT

Octal D-Type Latch with 3-State Output

The TC74ACT573 is an advanced high speed CMOS OCTAL LATCH fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

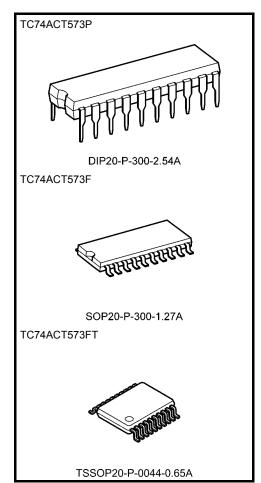
These 8-bit D-type latches are controlled by a latch enable (LE) and a output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

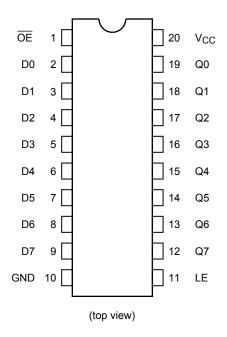
- High speed: $t_{pd} = 5.5 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V (max)}$ $V_{IH} = 2.0 \text{ V (min)}$
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24$ mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: t_{pLH} ≃ t_{pHL}
- Pin and function compatible with 74F573



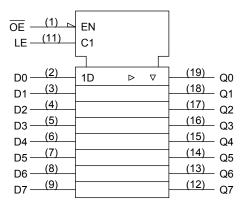
Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.)

Pin Assignment



IEC Logic Symbol



Truth Table

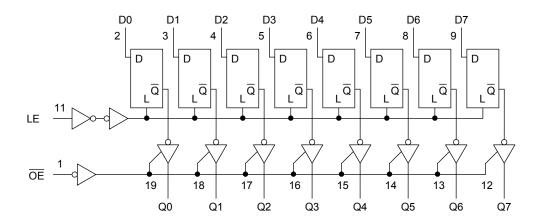
	Inputs	Output			
ŌE	LE	D	Q		
Н	Х	Х	Z		
L	L	Х	Qn		
L	Н	L	L		
L	Н	Н	Н		

X: Don't care

Z: High impedance

 Q_n : Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	l _{IK}	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	٧
Operating temperature	T _{opr}	−40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
- Characteriolico - Cyrribo					V _{CC} (V)	Min	Тур.	Max	Min	Max	O'mt
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	-	2.0	_	<	
Low-level input voltage	V _{IL}		_		4.5 to 5.5	_	_	0.8	-	0.8	٧
	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA		4.5	4.4	4.5	_	4.4	_	
High-level output voltage			I _{OH} = −24 mA		4.5	3.94	_	_	3.80	_	V
Ü			I _{OH} = −75 mA	(Note)	5.5	_	_	_	3.85	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I _{OL} = 24 mA	4.5	_	_	0.36	_	0.44	V	
vollago			I _{OL} = 75 mA	(Note)	5.5	_	_	_	_	1.65	
3-state output off-state current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	ı	_	±0.5	ı	±5.0	μΑ	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	I	_	±0.1	ı	±1.0	μΑ	
Quiescent supply current	Icc	V _{IN} = V _C	V _{IN} = V _{CC} or GND		5.5	1	_	8.0	ı	80.0	μΑ
	Ic	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	_	1.5	mA	

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = -40 to 85°C	Unit
			V _{CC} (V)	Limit	Limit	
Minimum pulse width (LE)	t _{w (H)}	_	5.0 ± 0.5	5.0	5.0	ns
Minimum set-up time	t _s	_	5.0 ± 0.5	3.0	3.0	ns
Minimum hold time	t _h	_	5.0 ± 0.5	2.0	2.0	ns



AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	Min	Тур.	Max	Min	Max	2
Propagation delay time	t _{pLH}	_	5.0 ± 0.5	_	6.3	10.5	1.0	12.0	ns
(LE-Q)	t _{pHL}								
Propagation delay time	t _{pLH}	_	5.0 ± 0.5	_	6.2	9.6	1.0	11.0	ns
(Dn-Q)	t _{pHL}								
Output enable time	t _{pZL}	_	5.0 ± 0.5	_	6.5	10.0	1.0	11.5	ns
	t _{pZH}								
Output disable time	t _{pLZ}	_	5.0 ± 0.5	_	6.5	8.8	1.0	10.0	ns
	t _{pHZ}								
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Output capacitance	C _{OUT}	_		_	10	_	_	_	pF
Power dissipation capacitance	C _{PD}		(Note)	_	22	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

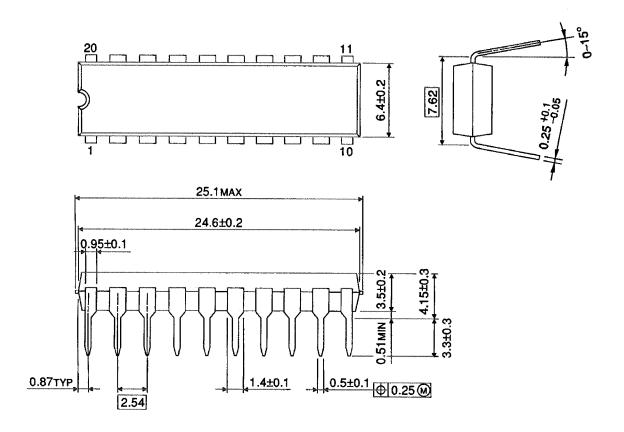
$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per latch)$$

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation:

$$C_{PD}$$
 (total) = 6 + 16·n

Package Dimensions

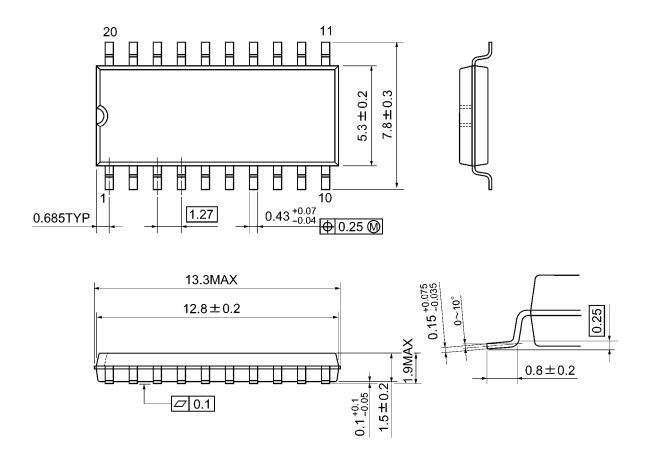
DIP20-P-300-2.54A Unit: mm



Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A Unit: mm

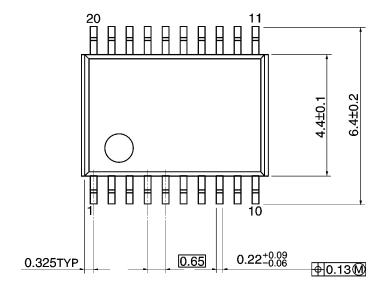


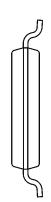
Weight: 0.22 g (typ.)

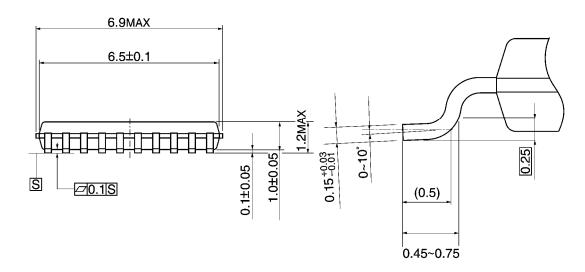
Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm







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Weight: 0.08 g (typ.)

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